CMOS Digital Integrated Circuits Silicon Monolithic

74VHC165FT

1. Functional Description

• 8-Bit Shift Register (P-IN, S-OUT)

2. General

The 74VHC165FT is an advanced high speed CMOS 8-BIT PARALLEL/SERIAL-IN, SERIAL-OUT SHIFT REGISTER fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

It consists of parallel-in or serial-in, serial-out 8-bit shift register with a gated clock input. When the SHIFT/ $\overline{\text{LOAD}}$ input is held high, the serial data input is enabled and the eight frip-frops perform serial shifting with each clock pulse.

When the SHIFT/LOAD input is held low, the parallel data is loaded synchronously into the register at positive going transition of the clock pulse.

The CK-INH input should be shifted high only when the CK input is held high.

An Input protection circuit ensures that 0 to 5.5 V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5 V to 3 V systems and on two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

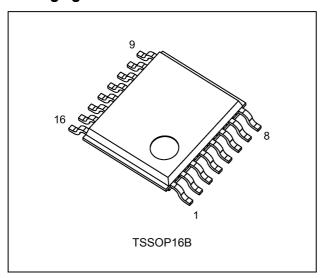
3. Features

- (1) AEC-Q100 (Rev. H) (Note 1)
- (2) Wide operating temperature range: $T_{opr} = -40$ to 125 °C
- (3) High speed: $f_{MAX} = 150 \text{ MHz}$ (typ.) at $V_{CC} = 5 \text{ V}$
- (4) Low power dissipation: $I_{CC} = 4.0 \mu A \text{ (max)}$ at $T_a = 25 \text{ °C}$
- (5) High noise immunity: $V_{NIH} = V_{NIL} = 28 \% V_{CC}$ (min)
- (6) Power-down protection is provided on all inputs.
- (7) Balanced propagation delays: $t_{PLH} \approx t_{PHL}$
- (8) Wide operating voltage range: $V_{CC(opr)} = 2.0 \text{ V}$ to 5.5 V
- (9) Pin and function compatible with 74 series (74AC/HC/AHC etc.) 165 type.

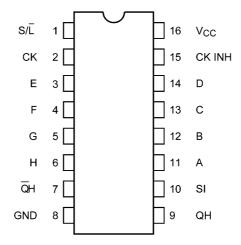
Note 1: This device is compliant with the reliability requirements of AEC-Q100. For details, contact your Toshiba sales representative.



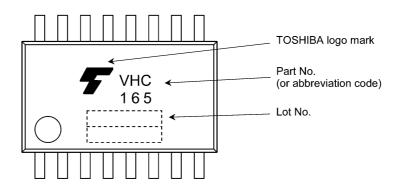
4. Packaging



5. Pin Assignment

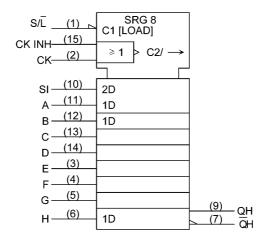


6. Marking





7. IEC Logic Symbol



8. Truth Table

		Inp	uts		Internal Outputs		Outputs	
SHIFT/ LOAD	CK INH	СК	SERIAL IN	PARALLEL A······H	QA	QB	QH	ıξ
L	Х	Х	Х	a·····h	а	b	h	١
Н	L		Н	Х	Н	QAn	QGn	QGn
Н	L		L	Х	L	QAn	QGn	
Н		L	Н	Х	Н	QAn	QGn	- QGn
Н		L	L	Х	L	QAn	QGn	- QGn
Н	Х	Н	Х	Х	No Change			
Н	Н	Х	Х	Х	No Change			

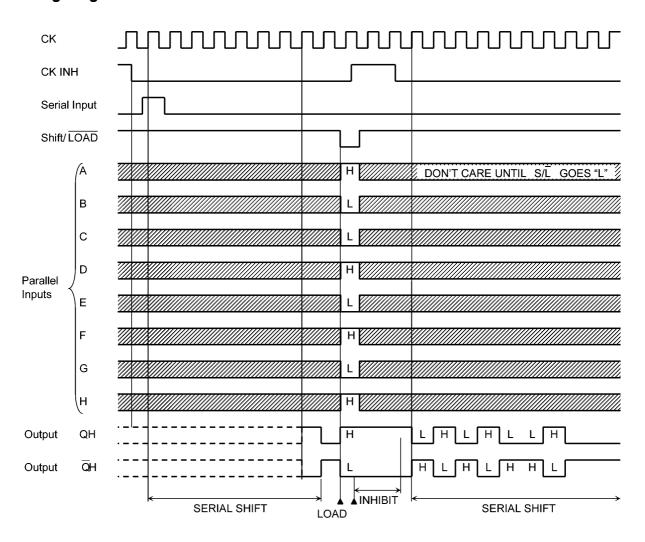
X: Don't care

a.....h: The level of steady state input voltage at inputs A through H respectively.

 $\mathsf{QA}_{n} \text{ to } \mathsf{QG}_{n} \text{: } \mathsf{The \ level \ of \ QA \ to \ QG, \ respectively, \ before \ the \ most \ recent \ positive \ transition \ of \ the \ CK.}$

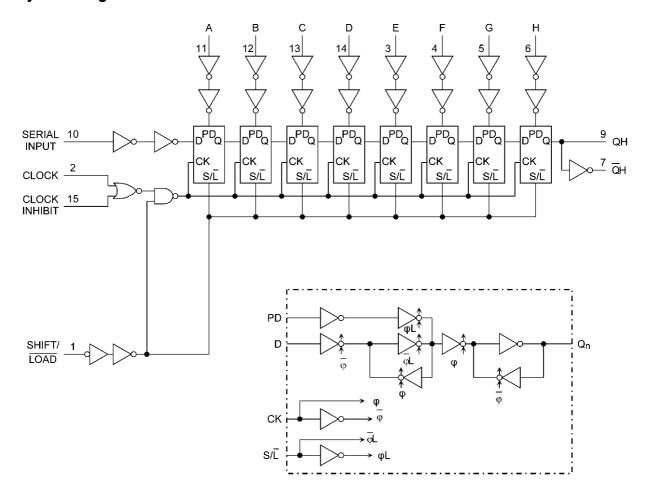


9. Timing Diagrams





10. System Diagram





11. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V _{CC}		-0.5 to 7.0	V
Input voltage	V _{IN}		-0.5 to 7.0	V
Output voltage	V _{OUT}		-0.5 to V _{CC} + 0.5	V
Input diode current	I _{IK}		-20	mA
Output diode current	I _{OK}		±20	mA
Output current	I _{OUT}		±25	mA
V _{CC} /ground current	I _{CC}		±50	mA
Power dissipation	P _D	(Note 1)	180	mW
Storage temperature	T _{stg}		-65 to 150	°C

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: 180 mW in the range of T_a = -40 to 85 °C. From T_a = 85 to 125 °C a derating factor of -3.25 mW/°C shall be applied until 50 mW.

12. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V _{CC}		2.0 to 5.5	V
Input voltage	V _{IN}		0 to 5.5	V
Output voltage	V _{OUT}		0 to V _{CC}	V
Operating temperature	T _{opr}		-40 to 125	°C
Input rise and fall times	dt/dv	V_{CC} = 3.3 ± 0.3 V	0 to 100	ns/V
		V _{CC} = 5 ± 0.5 V	0 to 20	

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.



13. Electrical Characteristics

13.1. DC Characteristics (Unless otherwise specified, T_a = 25 °C)

Characteristics	Symbol	Test Condition		V _{CC} (V)	Min	Тур.	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	_	
Low-level input voltage	V _{IL}	_		2.0	_		0.50	V
				3.0 to 5.5	_		$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	$V_{IN} = V_{IH}$ or V_{IL}	I_{OH} = -50 μ A	2.0	1.9	2.0	_	V
				3.0	2.9	3.0	_	
				4.5	4.4	4.5	_	
			I_{OH} = -4 mA	3.0	2.58	-	_	
			I_{OH} = -8 mA	4.5	3.94		_	
Low-level output voltage	V _{OL}	$V_{IN} = V_{IH}$ or V_{IL}	I _{OL} = 50 μA	2.0	_	0.0	0.1	V
				3.0	_	0.0	0.1	
				4.5	_	0.0	0.1	
			I_{OL} = 4 mA	3.0	_	_	0.36	
			I _{OL} = 8 mA	4.5	_		0.36	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_		±0.1	μΑ
Quiescent supply current	I _{CC}	$V_{IN} = V_{CC}$ or GND		5.5	_	_	4.0	μΑ

13.2. DC Characteristics (Unless otherwise specified, T_a = -40 to 85 °C)

Characteristics	Symbol	Test Con	dition	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.5	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V _{IL}	_		2.0	_	0.5	V
				3.0 to 5.5		$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			$I_{OH} = -4 \text{ mA}$	3.0	2.48	_	
			I_{OH} = -8 mA	4.5	3.80	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0	_	0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.44	
			I_{OL} = 8 mA	4.5	_	0.44	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5	_	±1.0	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	40.0	μΑ



13.3. DC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C)

Characteristics	Symbol	Test Conditio	n	V _{CC} (V)	Min	Max	Unit
High-level input voltage	V _{IH}	_		2.0	1.50	_	V
				3.0 to 5.5	$V_{CC} \times 0.7$	_	
Low-level input voltage	V _{IL}	_		2.0		0.50	V
				3.0 to 5.5		$V_{CC} \times 0.3$	
High-level output voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	I _{OH} = -50 μA	2.0	1.9	_	V
				3.0	2.9	_	
				4.5	4.4	_	
			I_{OH} = -4 mA	3.0	2.40	_	
			I_{OH} = -8 mA	4.5	3.70	_	
Low-level output voltage	V _{OL}	V _{IN} = V _{IH} or V _{IL}	I _{OL} = 50 μA	2.0		0.1	V
				3.0	_	0.1	
				4.5	_	0.1	
			I _{OL} = 4 mA	3.0	_	0.55	
			I_{OL} = 8 mA	4.5	_	0.55	
Input leakage current	I _{IN}	V _{IN} = 5.5 V or GND		0 to 5.5		±2.0	μΑ
Quiescent supply current	I _{CC}	V _{IN} = V _{CC} or GND		5.5	_	80.0	μΑ

13.4. Timing Requirements (Unless otherwise specified, T_a = 25 °C, Input: t_f = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)},t_{w(H)}$	_	3.3 ± 0.3	6.0	ns
(CK, CK INH)			5.0 ± 0.5	4.0	
Minimum pulse width	t _{w(L)}	_	3.3 ± 0.3	7.5	ns
(S/L)			5.0 ± 0.5	5.0	
Minimum setup time	t _S	_	3.3 ± 0.3	7.5	ns
(PI-S/L)			5.0 ± 0.5	5.0	
Minimum setup time	ts	_	3.3 ± 0.3	5.0	ns
(SI-CK, CK INH)			5.0 ± 0.5	4.0	
Minimum setup time	ts	_	3.3 ± 0.3	5.0	ns
(S/L-CK, CK INH)			5.0 ± 0.5	4.0	
Minimum hold time	t _h	_	3.3 ± 0.3	0.5	ns
(PI-S/L)			5.0 ± 0.5	1.0	
Minimum hold time	t _h	_	3.3 ± 0.3	0.0	ns
(SI-CK, CK INH)			5.0 ± 0.5	0.5	
Minimum hold time	t _h	_	3.3 ± 0.3	0.0	ns
(S/L-CK, CK INH)			5.0 ± 0.5	0.5	
Minimum removal time	t _{rem}	_	3.3 ± 0.3	5.0	ns
(CK INH-CK), (CK-CK INH)			5.0 ± 0.5	3.5	



13.5. Timing Requirements (Unless otherwise specified, T_a = -40 to 85 °C, Input: t_f = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	3.3 ± 0.3	7.0	ns
(CK, CK INH)			5.0 ± 0.5	4.0	
Minimum pulse width	t _{w(L)}	_	3.3 ± 0.3	9.0	ns
(S/L)			5.0 ± 0.5	6.0	
Minimum setup time	t _S	_	3.3 ± 0.3	8.5	ns
(PI-S/L)			5.0 ± 0.5	5.0	
Minimum setup time	t _S	_	3.3 ± 0.3	6.0	ns
(SI-CK, CK INH)			5.0 ± 0.5	4.0	
Minimum setup time	t _S	_	3.3 ± 0.3	6.0	ns
(S/L-CK, CK INH)			5.0 ± 0.5	4.0	
Minimum hold time	t _h	_	3.3 ± 0.3	0.5	ns
(PI-S/L)			5.0 ± 0.5	1.0	
Minimum hold time	t _h	_	3.3 ± 0.3	0.0	ns
(SI-CK, CK INH)			5.0 ± 0.5	0.5	
Minimum hold time	t _h	_	3.3 ± 0.3	0.0	ns
(S/L-CK, CK INH)			5.0 ± 0.5	0.5	
Minimum removal time	t _{rem}	_	3.3 ± 0.3	5.0	ns
(CK INH-CK), (CK-CK INH)			5.0 ± 0.5	3.5	

13.6. Timing Requirements (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_f = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width	$t_{w(L)}, t_{w(H)}$	_	3.3 ± 0.3	7.0	ns
(CK, CK INH)			5.0 ± 0.5	4.0	
Minimum pulse width	t _{w(L)}	_	3.3 ± 0.3	9.0	ns
(S/L)			5.0 ± 0.5	6.0	
Minimum setup time	t _S	_	3.3 ± 0.3	8.5	ns
(PI-S/L)			5.0 ± 0.5	5.0	
Minimum setup time	t _S	_	3.3 ± 0.3	6.0	ns
(SI-CK, CK INH)			5.0 ± 0.5	4.0	
Minimum setup time	t _S	_	3.3 ± 0.3	6.0	ns
(S/L-CK, CK INH)			5.0 ± 0.5	4.0	
Minimum hold time	t _h	_	3.3 ± 0.3	0.5	ns
(PI-S/L)			5.0 ± 0.5	1.0	
Minimum hold time	t _h	_	3.3 ± 0.3	0.0	ns
(SI-CK, CK INH)			5.0 ± 0.5	0.5	
Minimum hold time	t _h	_	3.3 ± 0.3	0.0	ns
(S/L-CK, CK INH)			5.0 ± 0.5	0.5	
Minimum removal time	t _{rem}	_	3.3 ± 0.3	5.0	ns
(CK INH-CK), (CK-CK INH)			5.0 ± 0.5	3.5	



13.7. AC Characteristics (Unless otherwise specified, $T_a = 25$ °C, Input: $t_r = t_f = 3$ ns)

Characteristics	Symbol	Note	Test Condition	V _{CC} (V)	C _L (pF)	Min	Тур.	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	9.9	15.4	ns
(CK, CK INH-QH, QH)					50	_	12.4	18.9	
				5.0 ± 0.5	15	_	6.6	9.9	
					50	_	8.1	11.9	
Propagation delay time (S/L-QH, QH)	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	9.9	15.8	ns
					50	_	12.4	19.3	
				5.0 ± 0.5	15	_	6.7	9.9	
					50	_	8.2	11.9	
Propagation delay time	t _{PLH} ,t _{PHL}		_	3.3 ± 0.3	15	_	9.2	14.1	ns
$(H-QH, \overline{Q}H)$					50		11.7	17.6	
				5.0 ± 0.5	15	_	5.9	9.0	
					50	_	7.4	11.0	
Maximum clock frequency	f _{MAX}		_	3.3 ± 0.3	15	65	85	_	MHz
					50	60	105	_	
				5.0 ± 0.5	15	110	150	_	
					50	95	130	_	
Input capacitance	C _{IN}		_			_	4	10	pF
Power dissipation capacitance	C _{PD}	(Note 1)	_			_	50		pF

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation. $I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{|N} + I_{CC}$

13.8. AC Characteristics (Unless otherwise specified, $T_a = -40$ to 85 °C, Input: $t_r = t_f = 3$ ns)

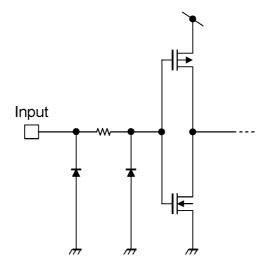
Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	18.0	ns
(CK, CK INH-QH, QH)				50	1.0	21.5	
			5.0 ± 0.5	15	1.0	11.5	
				50	1.0	13.5	
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	18.5	ns
(S/L-QH, QH)				50	1.0	22.0	
			5.0 ± 0.5	15	1.0	11.5	
				50	1.0	13.5	
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	16.5	ns
(H-QH, QH)				50	1.0	20.0	
			5.0 ± 0.5	15	1.0	10.5	
				50	1.0	12.5	
Maximum clock frequency	f _{MAX}	_	3.3 ± 0.3	15	55	_	MHz
				50	50	_	
			5.0 ± 0.5	15	90	_	
				50	85	_	
Input capacitance	C _{IN}	_				10	pF



13.9. AC Characteristics (Unless otherwise specified, T_a = -40 to 125 °C, Input: t_f = t_f = 3 ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	C _L (pF)	Min	Max	Unit
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	20.5	ns
(CK, CK INH-QH, QH)				50	1.0	24.0	
			5.0 ± 0.5	15	1.0	13.0	
				50	1.0	15.0	
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	21.0	ns
(S/L-QH, QH)				50	1.0	24.5	
			5.0 ± 0.5	15	1.0	13.0	
				50	1.0	15.0	
Propagation delay time	t _{PLH} ,t _{PHL}	_	3.3 ± 0.3	15	1.0	18.5	ns
(H-QH, QH)				50	1.0	22.0	
			5.0 ± 0.5	15	1.0	12.0	
				50	1.0	14.0	
Maximum clock frequency	f _{MAX}	_	3.3 ± 0.3	15	50	_	MHz
				50	45	_	
			5.0 ± 0.5	15	85	_	
				50	75		
Input capacitance	C _{IN}	_			_	10	pF

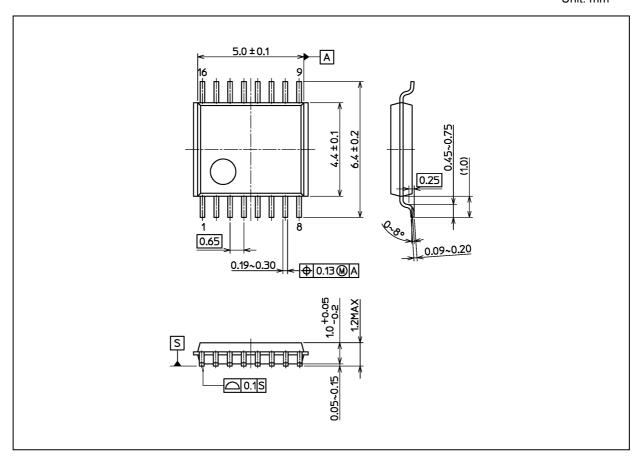
14. Internal Equivalent Circuit





Package Dimensions

Unit: mm



Weight: 0.055 g (typ.)

	Package Name(s)
Nickname: TSSOP16B	



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